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Date: Thursday, September 16, 2021  
Time: 16:00 - 17:00  
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<sup>1</sup>*Technische Universität Wien, Institute for Microelectronics, Austria;* <sup>2</sup>*Technische Universität Wien, Institute for Microelectronics / Nanolayers Research Computing, Ltd, Austria;* <sup>3</sup>*Technische Universität Wien, Institute for Microelectronics, Christian Doppler Lab., Austria*

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## Simulation & Modeling for Memory & Imaging Applications

Date: Thursday, September 16, 2021  
Time: 17:00 - 18:00  
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## Advanced Memory Devices

Date: Friday, September 17, 2021  
Time: 15:00 - 16:00  
Room: CHROME 1  
Chair(s): Qing-Tai Zhao; *Forschungszentrum Jülich*  
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Room: CHROME 1  
Chair(s): Nadine Collaert; *IMEC*  
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